# MSKSEMI 美森科













ESD

TVS

TSS

MOV

GDT

PLED

# RB521BS-30-MS

# **Product specification**





#### **Features**

- Extremelysmall surface mounting type. (SOD882).
- Low VF.
- High reliability.
- We declare that the material of product compliance with RoHS requirements and Halogen Free.
- S- prefix for automotive and other applications requiring unique site and control change requirements; AEC-Q101 qualified and PPAP capable.

#### **Reference News**

PACKAGE OUTLINE	Pin Configuration	Marking
		F *
SOD-882		



# MAXIMUM RATINGS(Ta = 25°C)

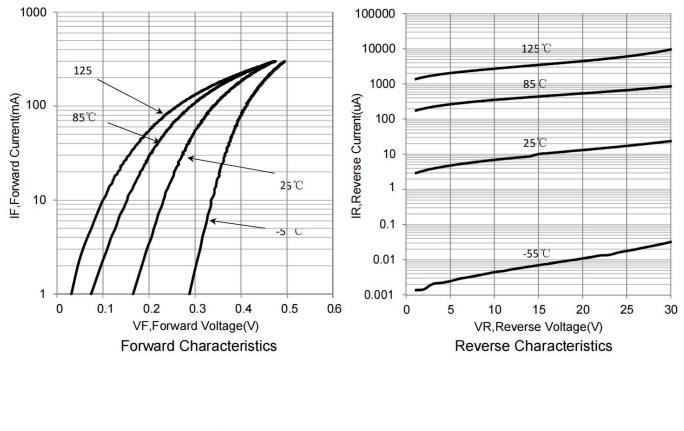
Parameter		Symbol	Limits	Unit
Reverse voltage (DC)		VR	30	V
Average rectifierd forward current		IO	200	m۸
Forward current surge peak (60Hz	1cyc)	IFSM	500	mA
Junction temperature		Tj	125	ŝ
Storage temperature		Tstg	-40~+125	°C

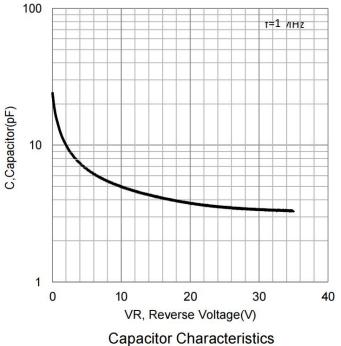
# **ELECTRICAL CHARACTERISTICS (Ta = 25°C)**

Characteristic	Symbol	Min.	Тур.	Max.	Unit
Forward voltage					
(IF =200mA)		-	-	0.5	
(IF =100mA)	VF	-	-	0.4	V
(IF =20mA)		-	-	0.38	
(IF =10mA)		-	-	0.35	
Reverse current	IR				
(VR =10V)	IK	-	-	30	μΑ



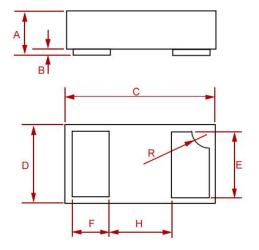
## **ELECTRICAL CHARACTERISTICS CURVES**





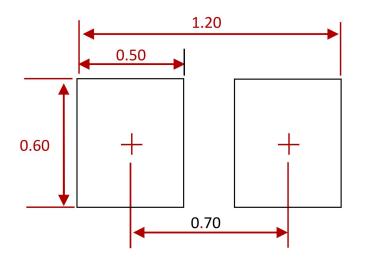


### PACKAGE MECHANICAL DATA



Dim	Inches		Millimeters	
Dim	MIN	МАХ	MIN	МАХ
А	0.0125	0.02	0.32	0.52
В	0.000	0.002	0.00	0.05
с	0.037	0.043	0.95	1.080
D	0.022	0.027	0.55	0.680
E	0.016	0.024	0.40	0.60
F	0.008	0.012	0.20	0.30
н	0.015Тур.		0.40	Тур.
R	0.001	0.005	0.05	0. 15

## **Suggested Pad Layout**



#### Note:

1.Controlling dimension: in millimeters.

2.General tolerance:±0.05mm.

3. The pad layout is for reference purposes only.

#### **REEL SPECIFICATION**

P/N	PKG	QTY
RB521BS-30-MS	SOD-882	10000



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